

HIGH-SPEED 4K x 9DUAL-PORT STATIC RAM

Features:

- True Dual-Ported memory cells which allow simultaneous reads of the same memory location
- High-speed access
 - Commercial: 12ns (max.)
 - Standard-power operation
 - IDT7014S
 - Active: 750mW (typ.)
- Fully asynchronous operation from either port
- ↑ TTL-compatible; single 5V (±10%) power supply
- Available in 52-pin PLCC and a 64-pin TQFP
- Green parts available, see ordering information

Description:

The IDT7014 is a high-speed 4K x 9 Dual-Port Static RAM designed to be used in systems where on-chip hardware port arbitration is not needed. This part lends itself to high-speed applications which do not rely on BUSY signals to manage simultaneous access.

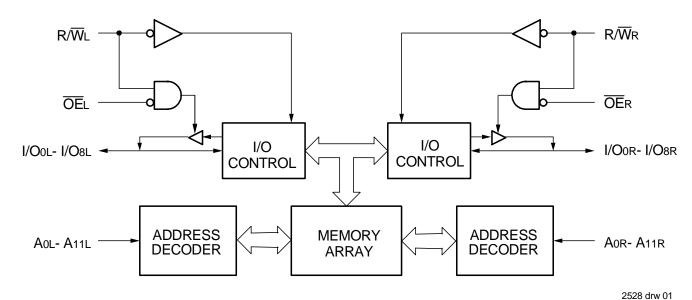
The IDT7014 provides two independent ports with separate control, address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. See functional description.

The IDT7014 utilizes a 9-bit wide data path to allow for parity at the user's option. This feature is especially useful in data communication applications where it is necessary to use a parity bit for transmission/reception error checking.

Fabricated using a high-performance technology, these Dual-Ports typically operate on only 750mW of power at maximum access times as fast as 12ns.

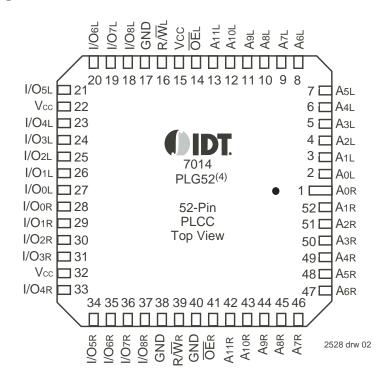
The IDT7014 is packaged in a 52-pin PLCC and a 64-pin thin quad flatpack, (TQFP).

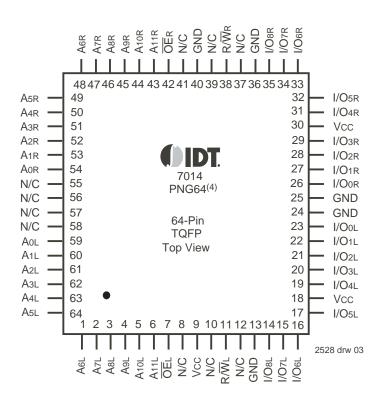
Functional Block Diagram



MAY 2019

Pin Configuration^(1,2,3)





NOTES:

- 1. All Vcc pins must be connected to power supply.
- All GND pins must be connected to ground supply.
- PLG52 package body is approximately .75 in x .75 in x .17 in. PNG64 package body is approximately 14mm x 14mm x 1.4mm.
- 4. This package code is used to reference the package diagram.



Commercial Temperature Range

Absolute Maximum Ratings (1)

Symbol	Rating	Commercial & Industrial	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7.0	V
VTERM ⁽²⁾	Terminal Voltage	-0.5 to +Vcc	V
TBIAS	Temperature Under Bias	-55 to +125	°C
Tstg	Storage Temperature	-65 to +150	۰C
ЮИТ	DC Output Current	50	mA

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- VTERM must not exceed Vcc + 10% for more than 25% of the cycle time or 10ns maximum, and is limited to ≤ 20mA for the period of VTERM ≥ Vcc + 10%.

Maximum Operating Temperature and Supply Voltage^(1,2)

)		
Grade	Ambient Temperature	GND	Vcc
Commercial	0°C to +70°C	0V	5.0V <u>+</u> 10%
Industrial	-40°C to +85°C	0V	5.0V <u>+</u> 10%

2528 tbl 02

NOTES:

2528 tbl 01

1. This is the parameter Ta. This is the "instant on" case temperature.

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vcc	Supply Voltage	4.5	5.0	5.5	V
GND	Ground	0	0	0	V
VIH	Input High Voltage	2.2	_	6.0(2)	٧
VIL	Input Low Voltage	-0.5 ⁽¹⁾	_	0.8	٧

NOTES:

- 2528 tbl 03
- 1. $V_{IL} \ge -1.5V$ for pulse width less than 10ns.
- 2. VTERM must not exceed Vcc + 10%.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range $^{(1)}$ (Vcc = 5.0V \pm 10%)

			7014S		
Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Iu	Input Leakage Current	Vcc = 5.5V, $VIN = 0V$ to Vcc	1	10	μA
ILO	Output Leakage Current	Vout = 0V to Vcc	-	10	μA
Vol	Output Low Voltage	lol = +4mA	_	0.4	V
Voh	Output High Voltage	Iон = -4mA	2.4	_	V

NOTE:

1. At $Vcc \le 2.0V$ input leakages are undefined.

2528 tbl 04



Commercial Temperature Range

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (Vcc = 5V ± 10%)

				_	4S12 I Only		4S15 I Only	
Symbol	Parameter	Test Condition	Version	Тур.	Max	Тур.	Max	Unit
Icc	Dynamic Operating	Outputs Open f = fMAX ⁽¹⁾	COM'L S	160	250	160	250	mA
	Current (Both Ports Active)	I = IMAX ^(*)	IND S	_	_	_	_	

2528 tbl 05a

			7014S20 Com'l & Ind		7014S25 Com'l Only			
Symbol	Parameter	Test Condition	Version	Тур.	Max	Тур.	Max.	Unit
Icc	Dynamic Operating	Outputs Open f = fMAX ⁽¹⁾	COM'L S	155	245	150	240	mA
	Current (Both Ports Active)	I = IMAX**	IND S	155	260	_	_	1

2528 tbl 05b

NOTES:

1. At f = fmax, address inputs are cycling at the maximum read cycle of 1/trc using the "AC Test Conditions" input levels of GND to 3V.

AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	3ns Max.
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	Figures 1,2 and 3

2528 tbl 06

2528 tbl 07

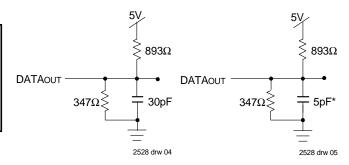


Figure 1. AC Output Test Load.

Figure 2. Output Test Load (for thz, twz, and tow) *Including scope and jig.

Capacitance⁽¹⁾

(Ta = +25°C, f = 1.0MHz) TQFP Package Only

Symbol	Parameter	Conditions ⁽²⁾	Max.	Unit
CIN	Input Capacitance	VIN = 3dV	9	pF
Соит	Output Capacitance	Vout = 3dV	10	pF

NOTES:

- 1. This parameter is determined by device characteristics but is not production
- 2. 3dv references the interpolated capacitance when the input and output signals swith from OV to 3V or from 3V to OV.

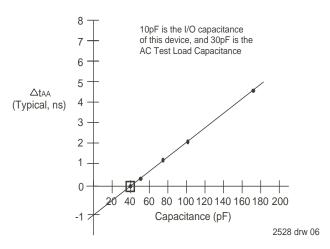


Figure 3. Typical Output Derating (Lumped Capacitive Load).



Commercial Temperature Range

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage

		7014S12 Com'l Only		7014S15 Com'l Only		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
READ CYCLE						
trc	Read Cycle Time	12	1	15	1	ns
taa	Address Access Time		12		15	ns
taoe	Output Enable Access Time		8		8	ns
tон	Output Hold from Address Change	3	1	3		ns
tLZ	Output Low-Z Time ^(1,2)	3		3	_	ns
tHZ	Output High-Z Time ^(1,2)		7	_	7	ns

2528 tbl 08a

		7014S20 Com'l & Ind		7014S25 Com'l Only		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
READ CYCLE						
trc	Read Cycle Time	20	1	25	1	ns
taa	Address Access Time	_	20	I	25	ns
taoe	Output Enable Access Time	_	10	I	12	ns
tон	Output Hold from Address Change	3	1	3		ns
tLZ	Output Low-Z Time ^(1,2)	3	_	3	_	ns
tHZ	Output High-Z Time ^(1,2)		9	_	11	ns

NOTES

2528 tbl 08b

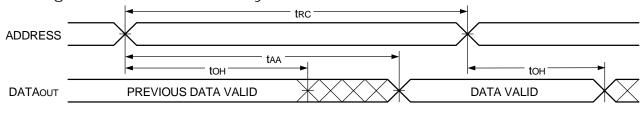
- 1. Transition is measured 0mV from Low or High-impedance voltage with Output Test Load (Figure 2).
- 2. This parameter is determined by device characterization, but is not production tested.



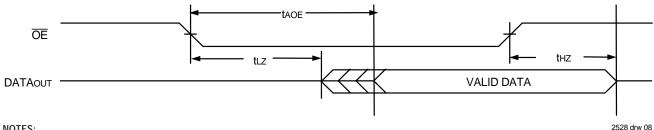
Commercial Temperature Range

2528 drw 07

Timing Waveform of Read Cycle No. 1, Either Side (1,2)



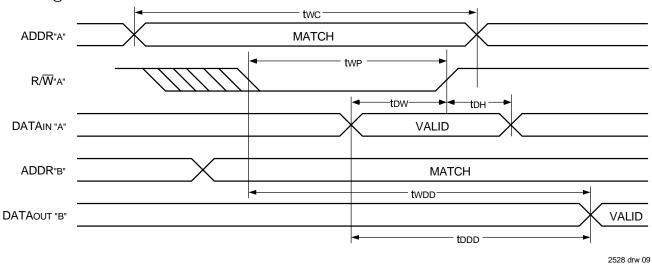
Timing Waveform of Read Cycle No. 2, Either Side^(1, 3)



NOTES:

- 1. R/\overline{W} = ViH for Read Cycles.
- 2. $\overline{OE} = VIL$.
- 3. Addresses valid prior to $\overline{\text{OE}}$ transition LOW.

Timing Waveform of Write with Port-to-Port Read^(1,2)



NOTES:

- 1. $R/\overline{W}^{"}B^{"} = V_{IH}$, read cycle pass through.
- 2. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is opposite from port "A".



Commercial Temperature Range

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage

		7014S12 Com'l Only		7014S15 Com'l Only		
Symbol	Parameter	Min.	Max.	Min.	Мах.	Unit
WRITE CYCLE						
twc	Write Cycle Time	12	1	15	_	ns
taw	Address Valid to End-of-Write	10	1	14	_	ns
tas	Address Set-up Time	0	-	0	_	ns
twp	Write Pulse Width	10	-	12	_	ns
twr	Write Recovery Time	1		1	_	ns
tow	Data Valid to End-of-Write	8	1	10	_	ns
tHZ	Output High-Z Time ^(1,2)		7	_	7	ns
тон	Data Hold Time ⁽³⁾	0	_	0	_	ns
twz	Write Enable to Output in High-Z ^(1,2)		7	_	7	ns
tow	Output Active from End-of-Write (1,2,3)	0	-	0		ns
twdd	Write Pulse to Data Delay ⁽⁴⁾		25	_	30	ns
todo	Write Data Valid to Read Data Delay ⁽⁴⁾		22		25	ns

2528 tbl 09a

		7014S20 Com'l & Ind		7014S25 Com'l Only			
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit	
WRITE CYCLI	E						
twc	Write Cycle Time	20		25	_	ns	
taw	Address Valid to End-of-Write	15		20	_	ns	
tas	Address Set-up Time	0		0	_	ns	
twp	Write Pulse Width	15		20	_	ns	
twr	Write Recovery Time	2	_	2	_	ns	
tow	Data Valid to End-of-Write	12	_	15	_	ns	
tHZ	Output High-Z Time ^(1,2)	_	9	_	11	ns	
tDH	Data Hold Time ⁽³⁾	0	_	0	_	ns	
twz	Write Enable to Output in High-Z ^(1,2)	_	9	_	11	ns	
tow	Output Active from End-of-Write ^(1,2,3)	0	_	0	_	ns	
twdd	Write Pulse to Data Delay ⁽⁴⁾		40	_	45	ns	
todo	Write Data Valid to Read Data Delay (4)	_	30	_	35	ns	

NOTES

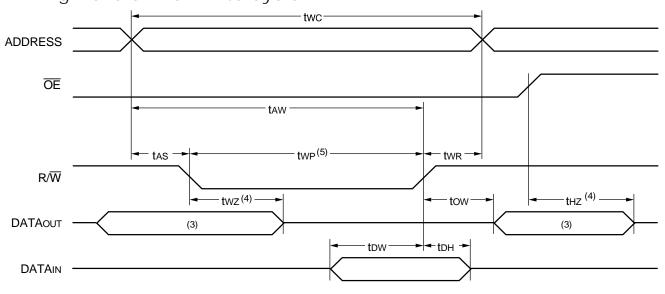
2528 tbl 09b

- 1. Transition is measured 0mV from Low or High-impedance voltage with Output Test Load (Figure 2).
- 2. This parameter is guaranteed by device characterization, but is not production tested.
- 3. The specification for ton must be met by the device supplying write data to the RAM under all operating conditions. Although ton and tow values will vary over voltage and temperature, the actual ton will always be smaller than the actual tow.
- 4. Port-to-port delay through RAM cells from writing port to reading port, refer to "Timing Waveform of Write With Port-to-Port Read".



Commercial Temperature Range

Timing Waveform of Write Cycle^(1,2,3,4,5)



NOTES:

- 2528 drw 10
- 1. $\mbox{R/$\overline{W}}$ must be HIGH during all address transitions.
- 2. two is measured from R/\overline{W} going HIGH to the end of write cycle.
- 3. During this period, the I/O pins are in the output state, and input signals must not be applied.
- 4. Transition is measured 0mV from the Low or High-impedance voltage with the Output Test Load (Figure 2).
- 5. If \overline{OE} is LOW during a R \overline{W} controlled write cycle, the write pulse width must be the larger of twp or (twz + tbw) to allow the I/O drivers to turn off data to be placed on the bus for the required tbw. If \overline{OE} is HIGH during an R \overline{W} controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twp.

Functional Description

The IDT7014 provides two ports with separate control, address, and I/O pins that permit independent access for reads or writes to any location in memory. It lacks the chip enable feature of CMOS Dual Ports, thus it operates in active mode as soon as power is applied. Each port has its own Output Enable control ($\overline{\text{OE}}$). In the read mode, the port's $\overline{\text{OE}}$ turns on the output drivers when set LOW. The user applications should avoid simultaneous write operations to the same memory location. There is no on-chip arbitration circuitry to resolve write priority and partial data from both ports may be written. READ/WRITE conditions are illustrated in Table 1.

Truth Table I - Read/Write Control

Left or Right Port ⁽¹⁾			
R∕W	ŌĒ	D0-8	Function
L	Χ	DATAIN	Data written into memory
Н	L	DATAOUT	Data in memory output on port
Х	Н	Z	High-impedance outputs

UOTE:

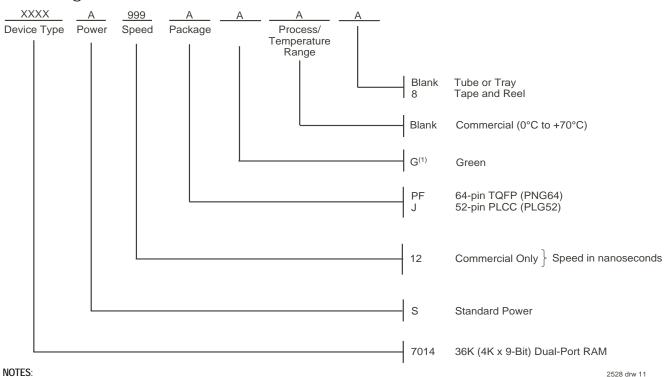
2528 tbl 10

AoL - A11L is not equal to AoR - A11R.
 'H' = HIGH,'L' = LOW, 'X' = Don't Care, and 'Z' = HIGH Impedance.



Commercial Temperature Range

Ordering Information



 $1. \ \ Green parts a valiable. For specific speeds, packages and powers contact your local sales of fice.$ LEAD FINISH (SnPb) parts are Obsolete. Product Discontinuation Notice - PDN# SP-17-02 Note that information regarding recently obsoleted parts is included in this datasheet for customer convenience.

Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
12	7014S12JG	PLG52	PLCC	С
	7014S12JG8	PLG52	PLCC	С
	7014S12PFG	PNG64	TQFP	С
	7014S12PFG8	PNG64	TQFP	С

Datasheet Document History

01/06/99: Initiated datasheet document history

Converted to new format

Cosmetic and typographical corrections Added additional notes to pin configurations

Page 2 Changed drawing format

Page 1 Corrected DSC number

06/03/99:



Datasheet Document History (con't)

03/10/00:		Added Industrial Temperature Ranges and deleted corresponding notes
	Page 1	Replaced IDT logo Made corrections to drawing
	r age r	Changed ±200mV to 0mV in notes
	Page 6	Made changes to drawings
05/19/00:	Page 3	Increased storage temperature parameter
		Clarified TA parameter
10/16/01:	Page 2	Added date revision for pin configuration
	Pages 4, 5 & 7	Removed Industrial temp values and column headings for 15 & 25ns speeds from
	D 0	DC and AC Electrical Characteristics
	Page 9	Removed Industrial temp offering from 15 & 25ns ordering information
	Dagos 1 9, 0	Added Industrial temp footnote to ordering information
04/04/06:	Pages 1 & 9 Page 1	Replaced тм logo with ® logo Added green availability to features
04/04/00.	Page 9	Added green indicator to ordering information
12/11/08:	Page 9	Removed "IDT" from orderable part number
08/18/14:	Page 9	Added Tape and Reel to Ordering Information
	Page 2 & 9	The package codes PN84-1 & J52-1 changed to PN84 & J52 respectively to match standard
	_	package codes
03/16/16:	Page 2	Changed diagram for the PN64 pin configuration by rotating package pin labels and pin
		numbers 90 degrees counter clockwise to reflect pin 1 orientation and added pin 1 dot at pin 1
		Removed the PN64 chamfer and aligned the top and bottom pin labels in the standard direction
		Added the IDT logo to the PN64 pin configurations and changed the text to be in
		alignment with new diagram marking specs
		Removed the date revision indicator for each pin configuration
	D 4	Updated footnote references for PN64 pin configuration
10/10/17	Page 4	Figure 3 Typical Output Derating Graph, corrected a typo
10/10/17:		Product Discontinuation Notice - PDN# SP-17-02
		Last time buy expires June 15, 2018
05/14/19:	Page 1	Removed Industrial speed grade offering and updated Commercial speed grade offering in Features
	Page 2	Changed diagram for the PLG52 pin configuration by rotating package pin labels and pin
		numbers 90 degrees clockwise to reflect pin 1 orientation and added pin 1 dot at pin 1
		Aligned the top and bottom pin labels in the standard direction
		Added the IDT logo to the PLG52 pin configuration and changed the text to be in
		alignment with new diagram marking specs Updated footnote references for PNG64 and PLG52
	Page 2 & 9	The package codes PN64 & J52 changed to PNG64 & PLG52 respectively to match standard
	rage z & /	package codes
	Page 9	Removed Industrial speed grade offering and updated Commercial speed grade offering in Ordering
	- 3	Information
		Removed industrial temp footnote from ordering information
		Revised LEAD FINISH note to indicate Obsolete
		Added Orderable Part Information

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